

## SOLAR CELLS

# Rational design of Lewis base molecules for stable and efficient inverted perovskite solar cells

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Lewis base molecules that bind undercoordinated lead atoms at interfaces and grain boundaries (GBs) are known to enhance the durability of metal halide perovskite solar cells (PSCs). Using density functional theory calculations, we found that phosphine-containing molecules have the strongest binding energy among members of a library of Lewis base molecules studied herein. Experimentally, we found that the best inverted PSC treated with 1,3-bis(diphenylphosphino)propane (DPPP), a diphosphine Lewis base that passivates, binds, and bridges interfaces and GBs, retained a power conversion efficiency (PCE) slightly higher than its initial PCE of ~23% after continuous operation under simulated AM1.5 illumination at the maximum power point and at ~40°C for >3500 hours. DPPP-treated devices showed a similar increase in PCE after being kept under open-circuit conditions at 85°C for >1500 hours.

Given their high power conversion efficiencies (PCEs), metal halide perovskite solar cells (PSCs) offer a route to lowering the cost of solar electricity (1–4). However, durability remains a major hurdle along the path to technological relevance (5–7) and must be assessed through accelerated degradation tests (8). Damp heat testing at 85°C in the dark at 85% relative humidity (RH), a test standard for crystalline silicon (Si) and thin-film photovoltaic (PV) modules, has been adopted for accelerating the durability test of PSCs (9–11). These tests are typically used to evaluate packaging rather than PV material durability. PSCs can also show degradation under photoexcited conditions (12), and especially under open-circuit (OC) conditions (13), that are more acute than one sees in standardized silicon tests. Mechanistically, such findings are often attributed to ion migration (14, 15) and charge accumulation at interfaces (9, 16, 17).

We studied the operating stability at 85°C under simulated 1-sun illumination (where 1 sun is defined as the standard illumination at AM1.5, or 1 kW m<sup>-2</sup>) and OC conditions—important test conditions under which PSCs have been studied to date only to a limited degree (18–20). Light- and heat-induced deg-

radation in PSCs is related to point defects formed at interfaces and grain boundaries (GBs) (14, 21). Moisture-induced degradation is curtailed using encapsulation (22), whereas the passivation of defects at interfaces and GBs within the perovskite film is required to improve the PCE and intrinsic durability of PSCs (11, 23–26). The use of phosphorus (P)-, nitrogen (N)-, sulfur (S)- and oxygen (O)-containing Lewis base molecules to form coordinate covalent bonds (dative bonds) that donate electrons to undercoordinated Pb atoms at interfaces and GBs has shown particular promise for increasing PSC durability (27–29).

Using density functional theory (DFT), we saw evidence that P-containing Lewis base molecules showed the strongest binding with uncoordinated Pb atoms. We thus pursued diphosphine-containing molecules, reasoning that these would provide additional binding and bridging at interfaces and GBs. For our experimental studies, we selected 1,3-bis(diphenylphosphino)propane (DPPP), a diphosphine Lewis base. We found that treating perovskites with a small amount of DPPP improves PCE and durability: Inverted (p-i-n) PSCs after DPPP treatment showed a champion PCE of 24.5%. A DPPP-treated PSC with an initial PCE of ~23% stabilized at ~23.5% after maximum power point tracking (MPPT) under continuous simulated AM1.5 illumination at ~40°C for >3500 hours. DPPP-stabilized PSCs showed no PCE degradation after being kept at OC and 85°C conditions for >1500 hours.

## Bonding interactions of Lewis bases

The P, N, S, and O atoms in Lewis base molecules donate electrons to the Lewis acid sites in perovskites, such as the undercoordinated Pb<sup>2+</sup> at perovskite surfaces, in order to form coordinate covalent bonds. In general, the

Lewis basicity, which is inversely proportional to electronegativity, is expected to determine the binding energy and the stabilization of interfaces and GBs. We compared binding energies of the prototypical Lewis bases trimethylphosphine (TMP), trimethylamine (TMA), dimethyl sulfide (DMS), and dimethyl ether (DME), with sp<sup>3</sup> hybridization to the surface of formamidinium lead iodide (FAPbI<sub>3</sub>) through DFT calculations (Fig. 1A). The calculated binding strength followed the order P > N > S > O, indicating that the electronegativity rule did not strictly apply—a finding we attribute to the remaining lone-pair electrons in the case of S and O after binding with perovskites. We also compared frequently reported Lewis base molecules with the sp<sup>2</sup> oxygen in the carbonyl groups and took acetone and methyl acetate (MeOAc) as examples in Fig. 1A (26, 30). The binding energies were similar to that of DME.

Lewis base molecules have mostly been used to passivate uncoordinated Pb atoms (24, 31–33). A Lewis base molecule with two electron-donating atoms can potentially bind and bridge interfaces and GBs, offering the potential to enhance the adhesion and strengthen the mechanical toughness of PSCs and provide additional benefits related to the durability of PSCs. For this reason, we selected DPPP, a diphosphine Lewis base molecule, in seeking to stabilize and passivate PSCs. As shown in Fig. 1B and fig. S1, a DPPP molecule has two P atoms with sp<sup>3</sup> hybridization in tetrahedral coordination. The lone-pair electrons occupy the missing vertex of the tetrahedron, and if donated to Lewis acids (metal cations) to form a covalent bond, the fully tetrahedral coordination would realize and gain more stabilization.

We calculated the binding of DPPP on the surfaces of FAPbI<sub>3</sub> both with lead(II) iodide (PbI<sub>2</sub>) and formamidinium iodide (FAI) terminations. Although DFT calculations predicted that the FAI-terminated surface would be more stable (34), experimental evidence showed that the PbI<sub>2</sub>-terminated surface is readily formed during the solvent treatment from depositing subsequent layers (35). DFT calculations also showed that DPPP was chemically bonded to the PbI<sub>2</sub>-terminated surface through P–Pb bond formation with a binding energy of 2.24 eV but was weakly bonded to the FAI-terminated surface by van der Waals interaction with a binding energy of 1.09 eV (Fig. 1, C and D). Moreover, the calculated binding energy of DPPP with perovskites in two adjacent slabs (3.08 eV) was larger than that in the same slab (2.24 eV) (Fig. 1, D and E). Similarly, the binding energy of DPPP with both the perovskite and NiO<sub>x</sub> slabs (4.31 eV) was larger than that in the same NiO<sub>x</sub> slab (3.28 eV) (Fig. 1F and fig. S2). Thus, DPPP was predicted to bind, bridge, and stabilize

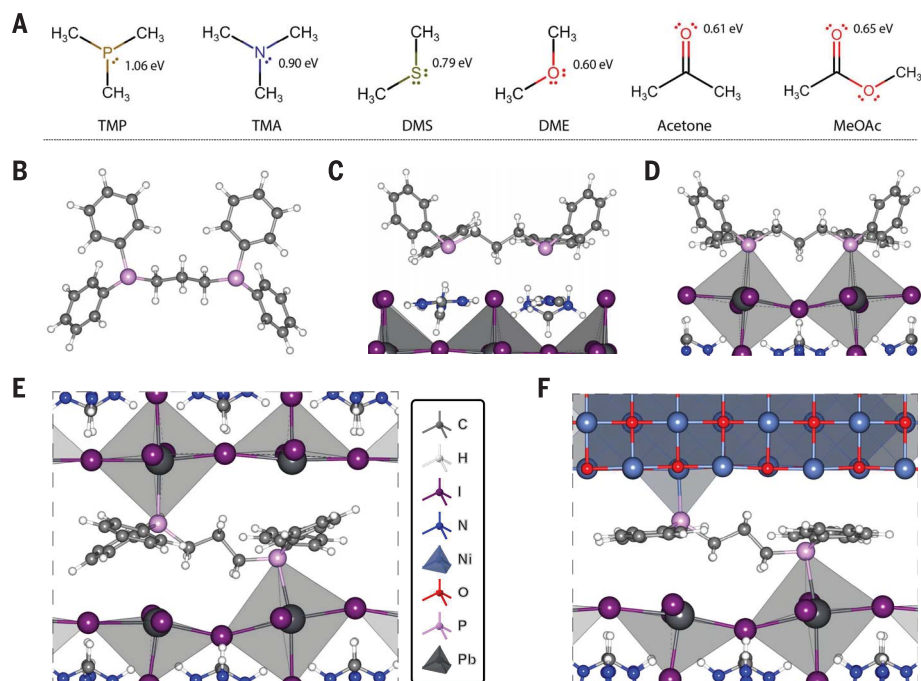
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perovskite GBs and the perovskite/ $\text{NiO}_x$  interface. DPPP molecules also provided hole transport channels through the P-terminated alkane chain of DPPP (fig. S3).

### Synthesis and structure

The interaction between DPPP molecules and  $\text{Pb}^{2+}$  is observed through the formation of a new adduct when a thin layer of DPPP is depos-

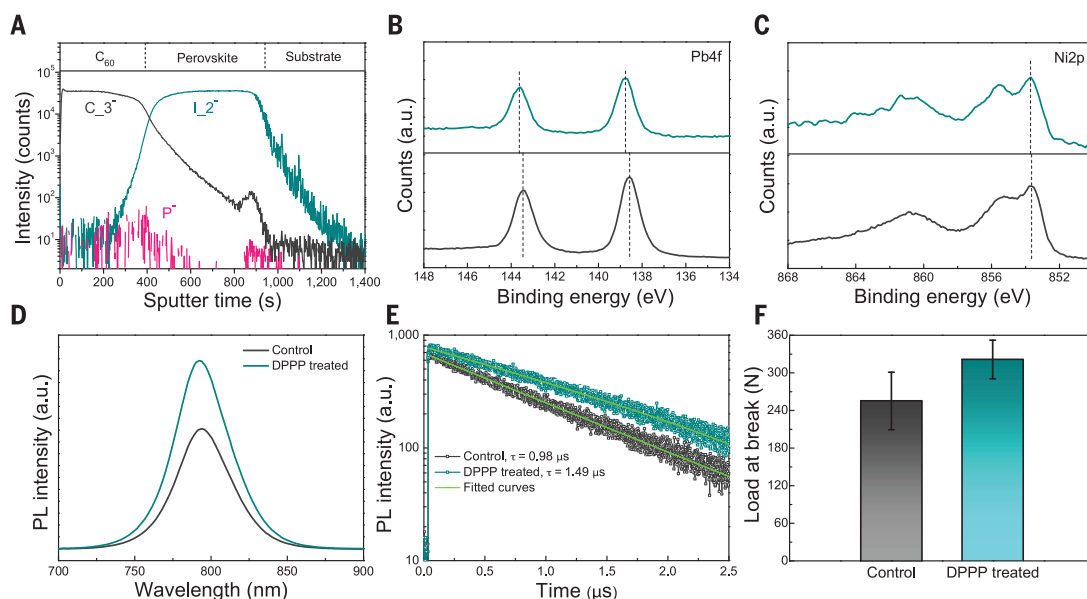
ited on a  $\text{PbI}_2$  layer (fig. S4). When fabricating devices, we deposited the FA-based perovskite layer on a DPPP-coated  $\text{NiO}_x$  hole transport layer. During the growth of perovskite films, some DPPP molecules redissolved and segregated at both the perovskite/ $\text{NiO}_x$  interface and the perovskite surface regions, as verified by the time-of-flight secondary ion mass spectrometry (TOF-SIMS) depth profiles shown in Fig. 2A. X-ray photoelectron spectroscopy (XPS) revealed that after DPPP treatment, the core levels of the elements in both perovskite and  $\text{NiO}_x$  shifted (Pb and Ni XPS spectra in Fig. 2, B and C, and the O, C, N, and I spectra in fig. S5). The universal shift of core levels caused by electrostatic interaction indicates the existence of DPPP at both interfaces. The DPPP treatment also slightly improved the crystallinity of perovskite films, as can be seen from the enhancement of grain domain size (fig. S6) and x-ray diffraction (XRD) peak intensity (fig. S7). DPPP treatment did not change the bandgap of the perovskite films (fig. S8). Photoluminescence (PL) and time-resolved PL spectroscopy (TRPL) spectra (Fig. 2, D and E) showed enhanced PL intensity and an  $\sim 50\%$  improvement in lifetime, from 0.98 to 1.49  $\mu\text{s}$ , for the DPPP-treated perovskite films, consistent with the expected reduction in nonradiative recombination and defect density upon Lewis base treatment (29, 36). We further verified that DPPP treatment enhanced the mechanical toughness of the perovskite/ $\text{NiO}_x$  interface. Perovskite films were deposited on a half-cell structure with and without DPPP treatment, protected by a thin polymethyl methacrylate (PMMA) layer, and adhered to a glass plate with epoxy (see details in the supplementary materials and fig. S9). A

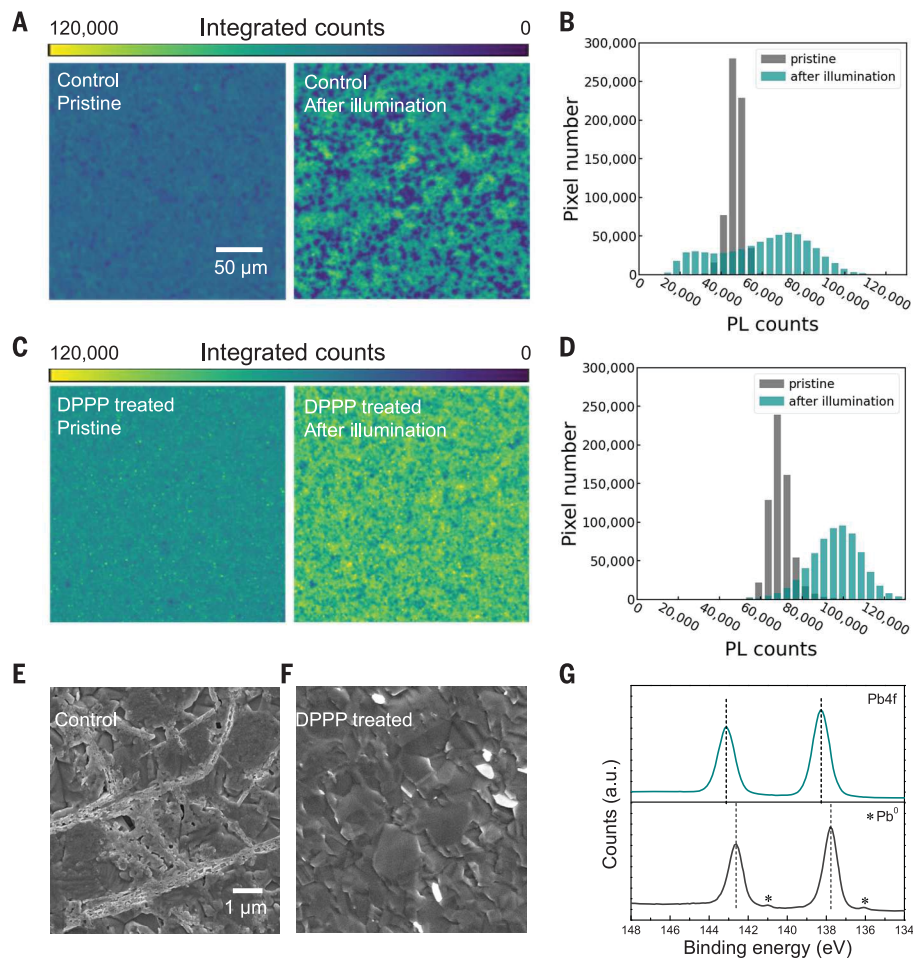


**Fig. 1. DFT-calculated DPPP binding with perovskites.** (A) Chemical structures of prototypical Lewis base molecules. The values shown are the DFT-calculated binding energies (in electron volts) of the Lewis base molecule bonded to the  $\text{FAPbI}_3$  surface with  $\text{PbI}_2$  termination. (B) Molecular structure of DPPP. The P atom of DPPP donates a lone-pair electron to the metal cation forming a coordinate covalent bond. Covalent bonding and van der Waals bonding for DPPP bound on  $\text{FAPbI}_3$  surfaces with (C) FAI and (D)  $\text{PbI}_2$  terminations, respectively. DPPP binds (E) two perovskite slabs and (F) perovskite and  $\text{NiO}_x$  substrate through chemical-bond formation between P and Pb or Ni atoms in a Lewis acid-base reaction.

### Fig. 2. Effects of DPPP on perovskite film quality and device performance.

(A) TOF-SIMS depth profile of a DPPP-treated sample showing that DPPP molecules segregate at both interfaces. XPS spectra comparing (B) binding energy of Pb-4f core levels of control and DPPP-treated samples and (C) binding energy of Ni-2p core levels of  $\text{NiO}_x$  before and after DPPP treatment. PL (D) and TRPL (E) spectra of control and DPPP-treated perovskite films measured from the film side. The samples were excited with a continuous-wave 633-nm laser at a fluence of  $1.5 \times 10^{17}$  photons  $\text{cm}^{-2} \text{s}^{-1}$ . (F) Histogram and standard deviation values of loads at break of 10 sets of control and DPPP-treated samples. a.u., arbitrary units.





**Fig. 3. Characterization of perovskite film stability before and after DPPP treatment. (A to D)** Hyperspectral PL images and histograms of control and DPPP-treated perovskite films before and after light aging. The PL images were taken from the buried interface side, and the PL count at each pixel refers to the integrated PL counts over the whole spectrum. **(E and F)** SEM top-view images taken from the buried interface of control and DPPP-treated perovskite films after light soaking. **(G)** XPS measured from the buried interface of control and DPPP-treated perovskite films after light soaking.

tensile load was applied to delaminate the films using the testing machine shown in fig. S10. After delamination, both the  $\text{NiO}_x$  and perovskite surfaces of the  $\text{NiO}_x$ /perovskite interface showed P signals, indicating that DPPP remained on both surfaces (fig. S11). The tensile force recorded during the delamination process (Fig. 2F) suggests that DPPP treatment enhanced the mechanical strength of the perovskite/ $\text{NiO}_x$  interface through the binding of DPPP at the interface.

Hyperspectral PL mapping measured from the buried interfaces and PL intensity histograms (Fig. 3, A to D) revealed an overall higher PL intensity of the DPPP-treated perovskite film that was consistent with the longer PL lifetimes and indicated reduced defect density as compared with the control perovskite films. The PL emission heterogeneity increased,

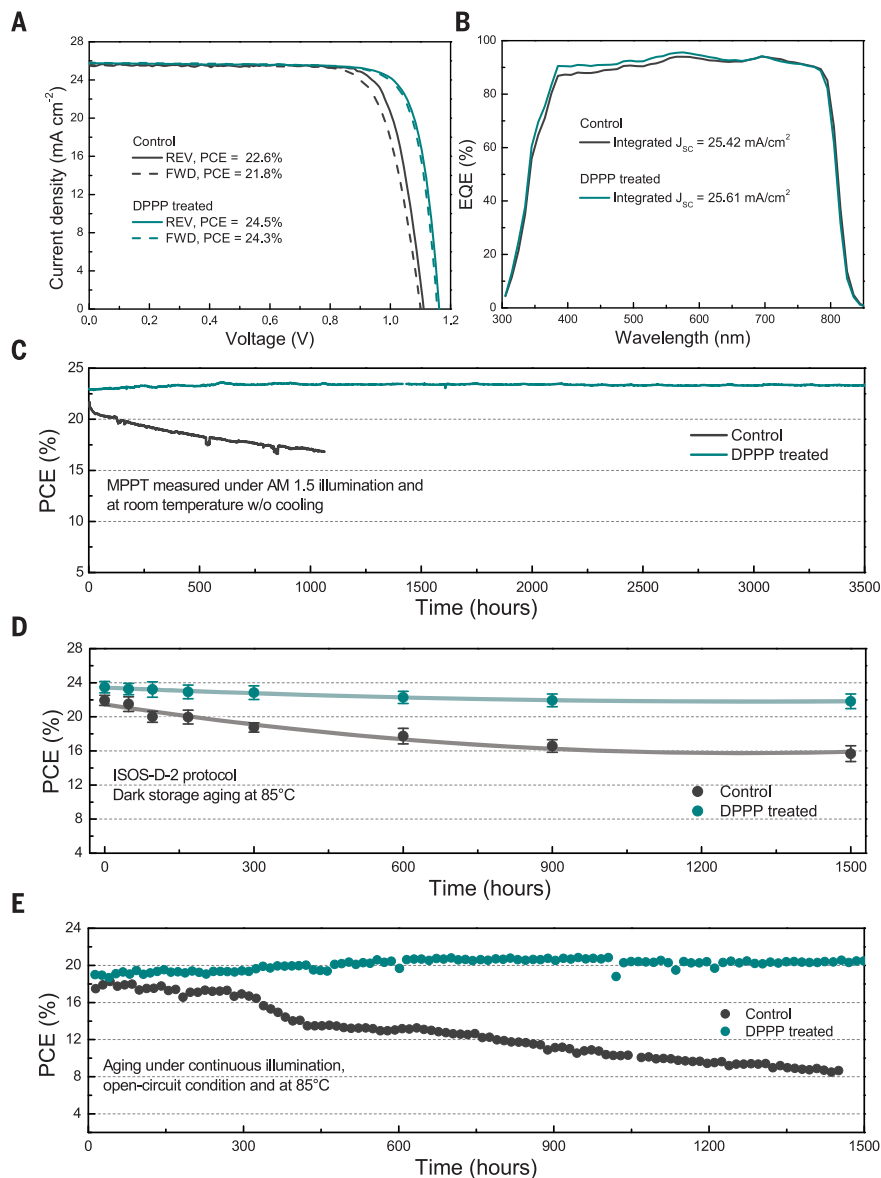
and more dark spots were observed over time in the control film after light aging (fig. S12). These dark spots showed lower PL emission intensity, and we attributed them to the initial sites of photodegradation at localized defects and local heterogeneities, which were more prevalent in the control sample without DPPP. PL decay takes place mostly in regions with low initial PL counts, whereas PL enhancement takes place in regions with high initial PL counts (fig. S13). This observation proves that local PL enhancement or decay in the control sample is associated with local defect heterogeneities. In comparison, the DPPP-treated films exhibited higher uniformity and better light stability, with most of the pixels showing photo-brightening with increased PL counts, rather than photo-decay with decreased PL counts, as was observed for the

control perovskite film (Fig. 3, B and D, and fig. S12). Scanning electron microscopy (SEM) images measured from the bottom surface show needle-shaped  $\text{PbI}_2$  crystals on the as-prepared control film, which is likely caused by the excess  $\text{PbI}_2$  added to the precursor solution (fig. S14A). The as-prepared DPPP-treated film showed distinct layered structures (fig. S14B), which we speculated could possibly be the Lewis acid-base adduct of  $\text{PbI}_2$  and DPPP. After aging, the  $\text{PbI}_2$  crystals in the control film decomposed and produced pinholes on the grains (Fig. 3E). In contrast, the DPPP-treated films exhibited much-suppressed degradation (Fig. 3F). Time-resolved mass spectroscopy was also conducted on control and DPPP-treated films under illumination to investigate the degradation process. The control sample showed the release of hydrogen iodide (HI) and iodide (I) species (fig. S15), which are by-products of the photoinduced decomposition and trigger irreversible chemical chain reactions that accelerate the decomposition of perovskites (37, 38). In addition to the iodide species, another perovskite decomposition by-product, metallic lead ( $\text{Pb}_0$ ), was also observed on the control film after light soaking. The XPS spectrum of the control film after light soaking showed two  $\text{Pb}_0$  peaks at  $\sim 136$  and  $\sim 141$  eV (Fig. 3G), whereas no  $\text{Pb}_0$  peaks were observed in DPPP-treated film. These results reveal that DPPP treatment could effectively suppress the photodecomposition at the  $\text{NiO}_x$ /perovskite interface, likely by reducing the density of reactive under-coordinated lead sites (halide vacancies) at the surface and interfaces.

### Solar cell fabrication and performance

We fabricated PSCs with the p-i-n configuration of glass/FTO/ $\text{NiO}_x$ /Me-4PACz/(with or without) DPPP/ $\text{FA}_{0.95}\text{Cs}_{0.05}\text{PbI}_3$ /PEAI/ $\text{C}_{60}$ / $\text{SnO}_2$ /Ag to show the effect of DPPP treatment on improving device performance and stability {FTO, fluorine-doped tin oxide; Me-4PACz, [4-(3,6-dimethyl-9H-carbazol-9-yl)butyl]phosphonic acid; PEA, phenethylammonium iodide}. Note that  $\text{NiO}_x$  was treated by a very thin layer of Me-4PACz to improve the reproducibility (fig. S16). The statistics of our device performance results are shown in fig. S17. A small amount of DPPP (1 or 2 mg/ml) consistently improved the open-circuit voltage ( $V_{\text{OC}}$ ) and fill factor (FF) across the comparison of 40 devices. Both the improvement in  $V_{\text{OC}}$  and FF are expected to accompany a reduction in surface recombination velocity through a reduction in surface defects (39), and they are also in qualitative agreement with the increase in film PL and PL lifetime upon treatment. Higher concentrations of DPPP (4 mg/ml) decreased short-circuit current density ( $J_{\text{SC}}$ ) and FF, which may have resulted from the overreaction between DPPP and perovskites. Figure 4A shows current





**Fig. 4. Performance and stability of control and DPPP-treated devices.** (A)  $J$ - $V$  curves of champion control and DPPP-treated devices. REV, reverse scan; FWD, forward scan. (B) EQE spectra of the corresponding control and DPPP-treated devices. (C) MPPT of control and DPPP-treated devices measured under continuous 1-sun illumination in an  $N_2$  environment at a temperature of  $\sim 40^\circ\text{C}$ . (D) Thermal stress test of control and DPPP-treated devices aged at  $85^\circ\text{C}$  following the ISOS-D-2 protocol. (E) Tracking of control and DPPP-treated devices measured at  $85^\circ\text{C}$  and under continuous  $\sim 0.9$ -sun illumination and OC condition.

density-voltage ( $J$ - $V$ ) scans of the champion control and DPPP-treated (2 mg/ml) devices with  $0.1\text{ cm}^2$  aperture masks under forward and reverse scans. The PCE of the DPPP-treated device improved from 22.6 to 24.5%, with  $V_{OC}$  increasing from  $\sim 1.11$  to  $\sim 1.16$  V and FF increasing from  $\sim 79$  to  $\sim 82\%$  (see detailed device parameters in table S1). External quantum efficiency (EQE) spectra (Fig. 4B) verified the  $J_{sc}$  values obtained from the  $J$ - $V$  measurement. The enhanced EQE at short wavelengths also indicates improved carrier extraction at the front interface, which may be associated

with the passivated interface achieved through the use of DPPP. We also fabricated PSCs with a larger active area ( $1.05\text{ cm}^2$ ) to validate the benefits of DPPP treatment. The target devices with DPPP treatment also showed overall improvement in device parameters (fig. S18), with the champion target device showing PCEs of 23.9 and 23.6% under reverse and forward scans, respectively (fig. S19 and table S2). The improvement on FF and  $V_{OC}$  confirmed the reduction in defect density at the  $\text{NiO}_x$ /perovskite front interface after DPPP treatment.

For durability tests, we replaced the Ag electrodes with Cr-Cu alloy to avoid instability caused by Ag corrosion and diffusion but slightly lowered the device efficiency (by  $\sim 4\%$ ) (fig. S20). We used  $0.1\text{ cm}^2$  aperture masks for solar cells when conducting all the stability tests. We first tested the effect of DPPP on device stability by MPPT under continuous 1-sun illumination in an  $N_2$  environment at a temperature of  $\sim 40^\circ\text{C}$ . As shown in Fig. 4C, the DPPP-treated device exhibited an initial PCE of  $\sim 23\%$ , which increased to  $\sim 23.5\%$  after  $\sim 450$  hours and remained unchanged after 3500 hours. The increased PCE resulted from the increased voltage at maximum power point (fig. S21). The increased voltage is likely due to the light-induced annihilation of halide defects (10, 40–43). However, the PCE of the control device decreased to  $<80\%$  of its initial PCE after 1000 hours. The film area of the control PSC turned dark yellow, indicating the decomposition of perovskite to  $\text{PbI}_2$  after 3500 hours (fig. S22). In contrast, the film area of the DPPP-treated device remained dark, indicating a more-stabilized perovskite after DPPP treatment.

We then conducted accelerated durability tests at elevated temperatures. We kept the PSCs in a dark oven at  $85^\circ\text{C}$  and in the ambient atmosphere and measured the PCEs periodically for the thermal stress test (ISOS-D-2 protocol). We tested 18 PSCs and summarize their statistics in fig. S23. The average PCEs and their corresponding standard deviations (Fig. 4D) reveal that the DPPP-treated devices retain, on average,  $\sim 90\%$  of their initial PCE after 1500 hours, whereas, in contrast, the average PCE of the control devices dropped to  $<90\%$  after 168 hours.

We conducted a more rigorous accelerated durability test under the OC condition and continuous  $\sim 0.9$ -sun illumination. The devices were kept in an oven at a temperature of  $85^\circ\text{C}$  and humidity of  $\sim 65\%$  and measured every 208 s. The devices measured at  $85^\circ\text{C}$  showed slightly lower PCEs, possibly owing to the negative temperature coefficient (fig. S24). The PCE was stable for the first  $\sim 300$  hours and then slightly increased to  $\sim 108\%$  of its initial value and showed no degradation after 1500 hours (Fig. 4E). However, the control device degraded rapidly after 400 hours, dropping to  $\sim 80\%$  of its initial PCE. Two more DPPP-treated PSCs were measured to validate the improved stability by DPPP treatment (fig. S25). The photos of devices after 1500 hours of illumination are shown in fig. S26. The glass-side view of the control film turned gray, which was likely the result of delamination of the perovskite film at the  $\text{NiO}_x$ /perovskite front interface and the degradation of the perovskite layer. In contrast, the DPPP-treated device showed partial delamination on the edge but remained dark over most of the film area.

## Discussion

Taking experimental findings together with DFT studies, we offer that DPPP molecules strengthen the NiO<sub>x</sub>/perovskite interface and stabilize the perovskite phase. The robust binding between the NiO<sub>x</sub> and perovskite enabled by DPPP modification appears to be an enabler of the stable operation of PSCs under outdoor conditions. The measured stability under accelerated testing conditions indicates a benefit from DPPP in the form of improved device stability and provides ways of realizing commercialization of PSCs.

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## SUPPLEMENTARY MATERIALS

[science.org/doi/10.1126/science.ade3970](https://science.org/doi/10.1126/science.ade3970)  
Materials and Methods  
Figs. S1 to S26  
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References

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